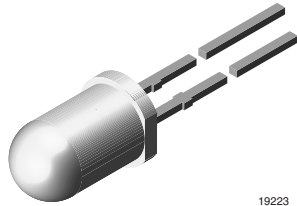


High Efficiency Blue LED, \varnothing 5 mm Untinted Non - Diffused Package



FEATURES

- GaN on SiC technology
- Standard \varnothing 5 mm T-1 $\frac{3}{4}$ package
- Small mechanical tolerances
- Small viewing angle
- Very high intensity
- Luminous intensity categorized
- ESD class 1
- Lead (Pb)-free device



DESCRIPTION

This device has been redesigned in 1998 replacing SiC by GaN technology to meet the increasing demand for high efficiency blue LEDs.

It is housed in a 5 mm waterclear plastic package.

All packing units are categorized in luminous intensity groups. That allows users to assemble LEDs with uniform appearance.

APPLICATIONS

- Status lights
- OFF/ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: 5 mm
- Product series: standard
- Angle of half intensity: $\pm 4^\circ$

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
TLHB5800	Blue, $I_V > 130$ mcd	GaN on SiC
TLHB5802	Blue, $I_V = (320 \text{ to } 860)$ mcd	GaN on SiC

ABSOLUTE MAXIMUM RATINGS ¹⁾ TLHB580.				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
DC Forward current	$T_{amb} \leq 65^\circ\text{C}$	I_F	20	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	I_{FSM}	0.1	A
Power dissipation	$T_{amb} \leq 65^\circ\text{C}$	P_V	100	mW
Junction temperature		T_j	100	$^\circ\text{C}$
Operating temperature range		T_{amb}	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 5$ s, 2 mm from body	T_{sd}	260	$^\circ\text{C}$
Thermal resistance junction/ ambient		R_{thJA}	350	K/W

Note:

¹⁾ $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLHB580., BLUE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity ²⁾	$I_F = 20 \text{ mA}$	TLHB5800	I_V	130	380		mcd
		TLHB5802	I_V	320		860	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		λ_d		466		nm
Peak wavelength	$I_F = 10 \text{ mA}$		λ_p		428		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		ϕ		± 4		deg
Forward voltage	$I_F = 20 \text{ mA}$		V_F		3.9	4.5	V
Reverse voltage	$I_R = 10 \mu\text{A}$		V_R	5			V

Note:

1) $T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

2) In one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

TYPICAL CHARACTERISTICS

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

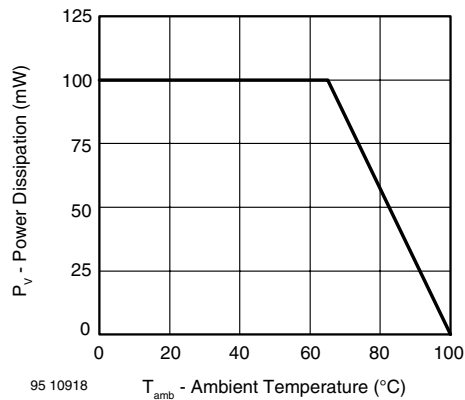


Figure 1. Power Dissipation vs. Ambient Temperature

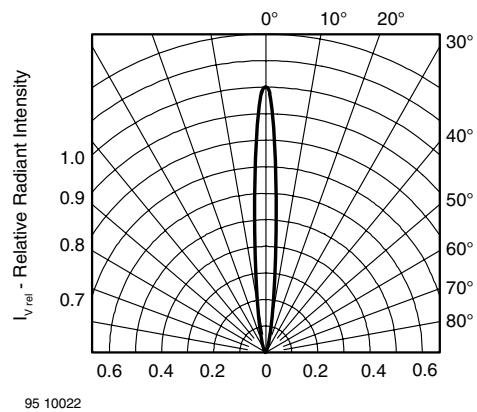


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

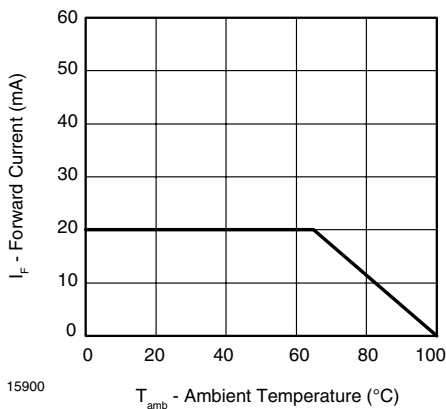


Figure 2. Forward Current vs. Ambient Temperature

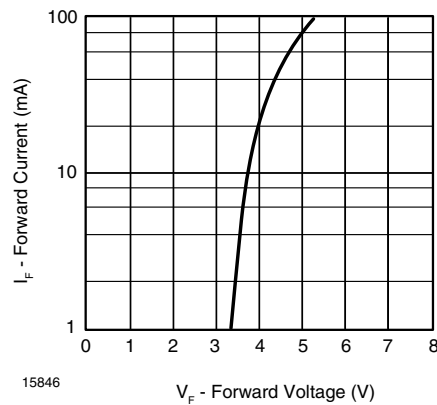


Figure 4. Forward Current vs. Forward Voltage

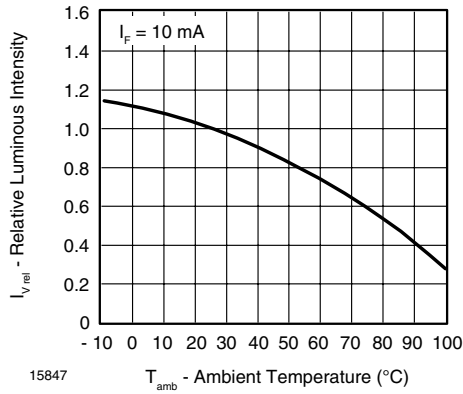


Figure 5. Rel. Luminous Flux vs. Ambient Temperature

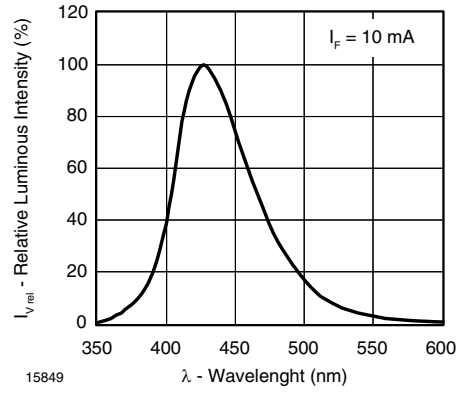


Figure 7. Relative Intensity vs. Wavelength

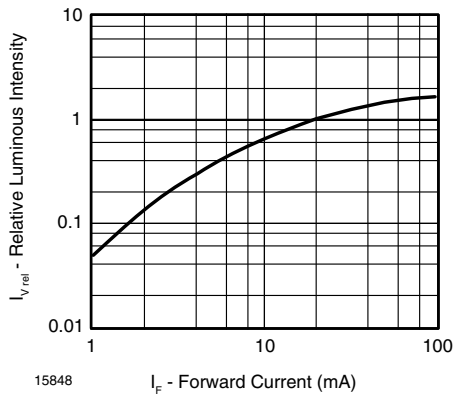
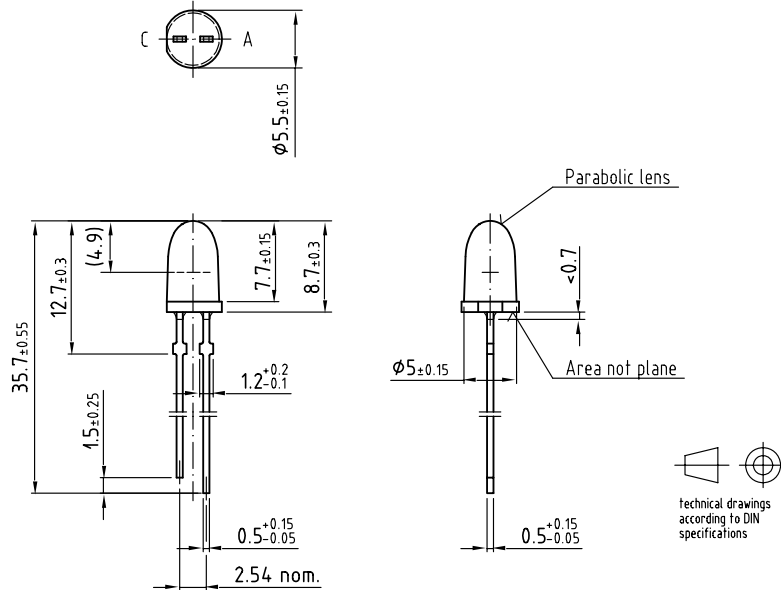


Figure 6. Relative Luminous Flux vs. Forward Current

PACKAGE DIMENSIONS in millimeters



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